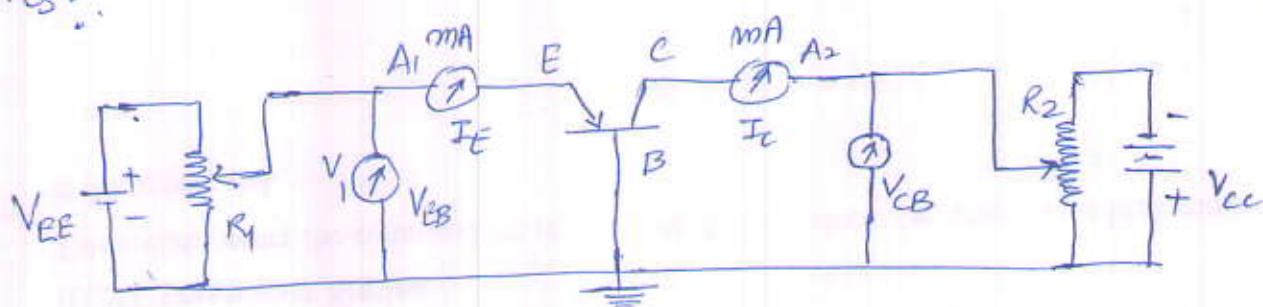
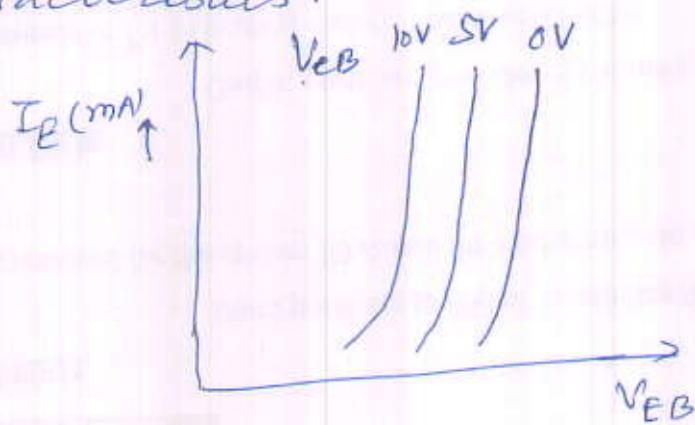


Q1. Explain input and output characteristics of common base configuration of transistor. 3

Ans:



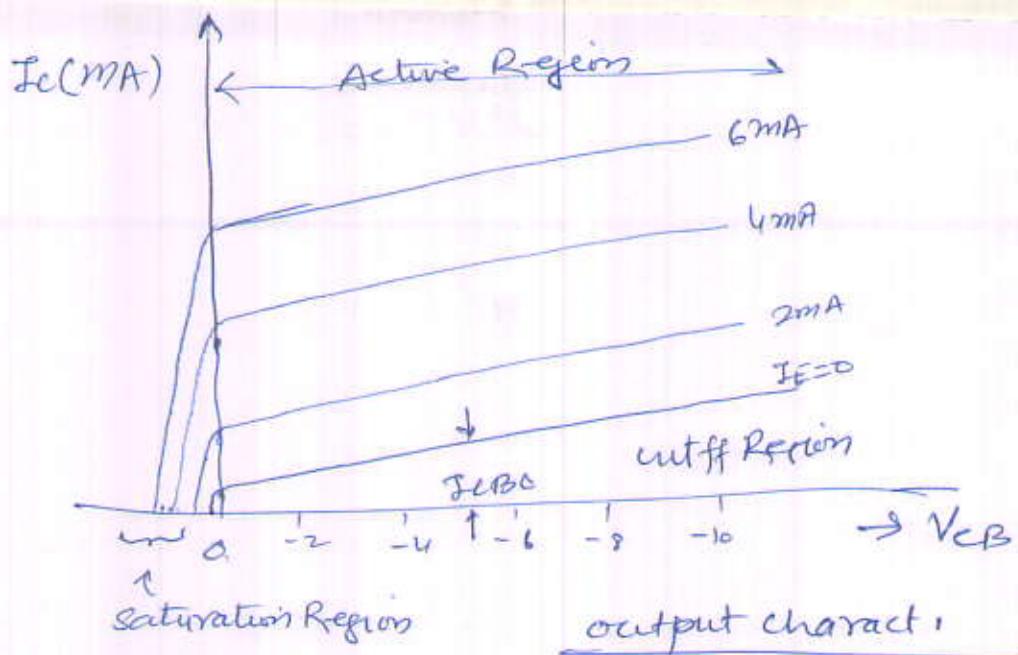
(i) Input characteristics: The curve between emitter current  $I_E$  and emitter base voltage  $V_{EB}$ , at constant collector base voltage  $V_{CB}$  represents the input characteristics.



- (i) There exists a cut-in, offset or threshold voltage  $V_{EB}$  below which the emitter current is very small
- (ii) The emitter current  $I_E$  increases rapidly with small increase in emitter base voltage  $V_{EB}$ . This shows that the input resistance is very small.

Output characteristics: The curve between collector current  $I_C$  and collector base voltage  $V_{CB}$  at constant emitter current  $I_E$  represents output characteristics.

- (i) In active region  $I_C$  is independent of collector voltage but depends only on  $I_E$
- (ii) In cutoff region small  $I_C$  flows when  $I_E \neq 0$
- (iii) Saturation region: When  $I_C$  flows even when  $V_{CB} \approx 0$



Q.2. Explain (i) Thermal runaway  
 (ii) Thermal stability

Ans.

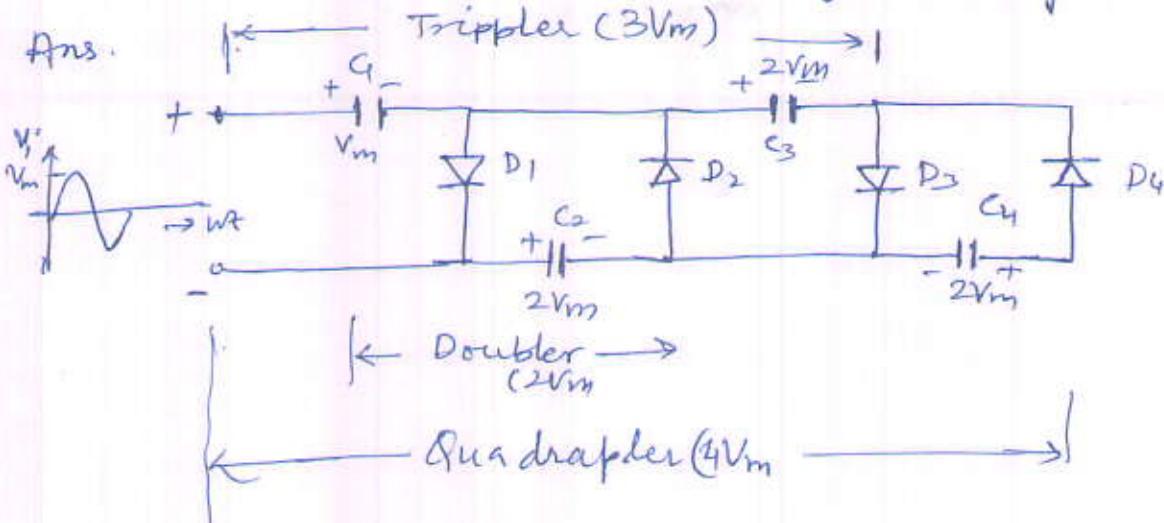
(i) Thermal runaway: When collector current flows in a transistor, it is heated i.e. its temperature increases. If no stabilization is done, the collector leakage current also increases. This further increases transistor temperature. Consequently, there is a further increase in leakage current. The action become cumulative and the transistor may ultimate burnout. This self destruction of transistor is known as thermal runaway.

(ii) To maintain the operating point stable against the variation of temperature, individual variation and thermal runaway, is known as thermal stability or stabilization.

$$\text{Stability factor } S = \frac{\Delta I_c}{\Delta T_{CO}}$$

When  $\propto S$  is smaller, higher the stability.

Q3. Write a short note on voltage multiplier?



In the above arrangement of voltage multiplier during positive half cycle, the diode  $D_1$  conducts charging  $C_1$  to  $V_m$  (Peak value) with shown polarity. In the first negative half cycle, the diode  $D_2$  conducts so that  $C_2$  gets charged to voltage  $2V_m$  because the input voltage  $V_m$  is in series with the capacitor  $C_1$  voltage  $V_m$ . In this process the charge on capacitor  $C_1$  starts discharging. In the second positive half cycle the diode  $D_1$  and  $D_2$  are forward biased and conducts. During second negative half cycle, the diode  $D_2$  and  $D_4$  will conduct charging  $C_4$  to a voltage  $2V_m$ .

$$V_{C_4} = V_m - V_{C_2} + V_{C_3} + V_{C_1}$$

$$= 2V_m$$

Now voltage across  $C_1, C_2, C_3$  and  $C_4$  are  $V_m, 2V_m, 2V_m$  and  $2V_m$  respectively.

So we can take output as our requirement across  $C_2$  (doubler), across  $C_1 \& C_3$  (Tripper) and across  $C_2$  and  $C_4$  (quadrapter)

Q4. Define

- (i) stability factor (ii) operating point

Ans: Stability factor

It is defined as rate of change of collector current  $I_C$  with respect to reverse saturation current  $I_{C0}$ , keeping  $\beta$  and  $V_{BE}$  constant.

$$S = \frac{\Delta I_C}{\Delta I_{C0}}$$

stability factor  $S_B$  rate of change of  $I_C$  with respect to  $\beta$  keeping  $I_{C0}$  and  $V_{BE}$  - constant

stability factor  $S_V$  rate of change of  $I_C$  with respect to  $V_{BE}$ , keeping  $I_{C0}$  and  $\beta$  - constant

Operating point It is a point on dc load line which represents the value of  $I_C$  and  $V_{CE}$  that exists in a transistor circuit when no signal is applied. It is also known as quiescent point or working point.